

A Switch-per-Phase PWM Current Source Converter Topology for Variable Reluctance Motor Drive

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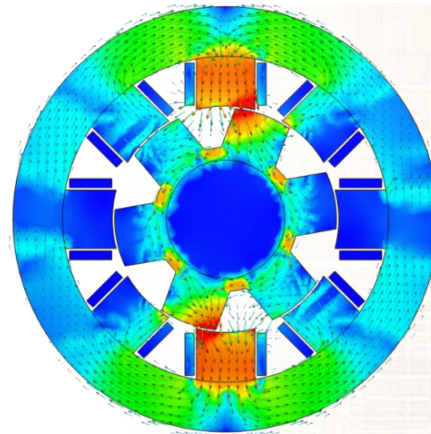
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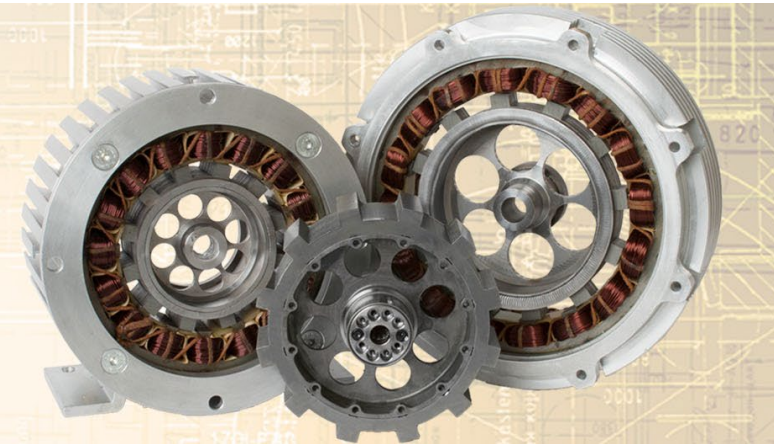


Introduction: Switched Reluctance Machine

- Rotor: simple laminated steel, no winding, no magnets
- Stator: concentrated windings, easy to manufacture



Torque Generation of SRM[1*]



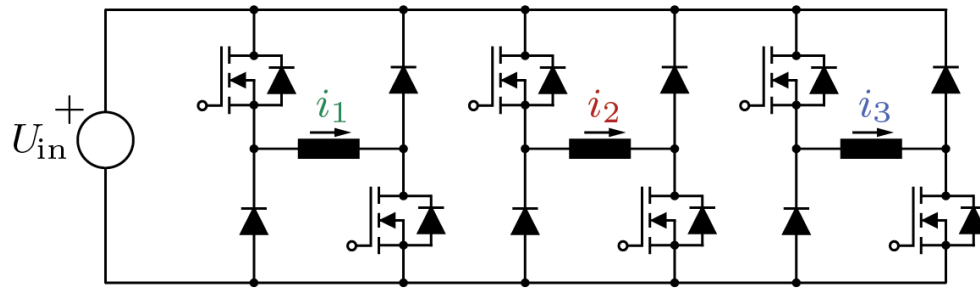
Stator and Rotor [2*]

- Magnet-free machine → low cost, no rare-earth dependency, high mechanical and thermal robustness
- Torque production relies on rotor position and phase excitation

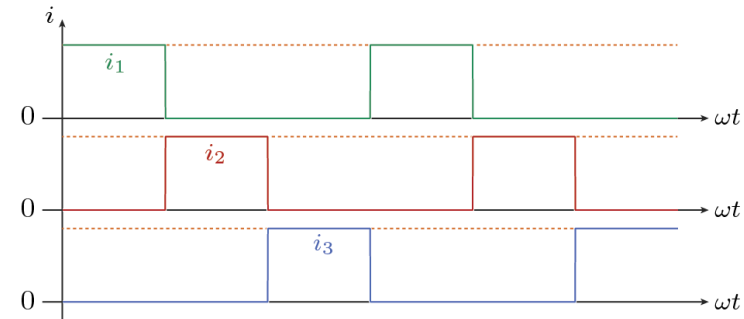


Introduction: Conventional SRM Drive – Asymmetric H-Bridge

- Asymmetrical H-Bridge generates **pulsed phase currents** due to switched excitation
- Requires fast current control bandwidth to achieve efficient torque regulation



Asymmetric H-Bridge Circuit



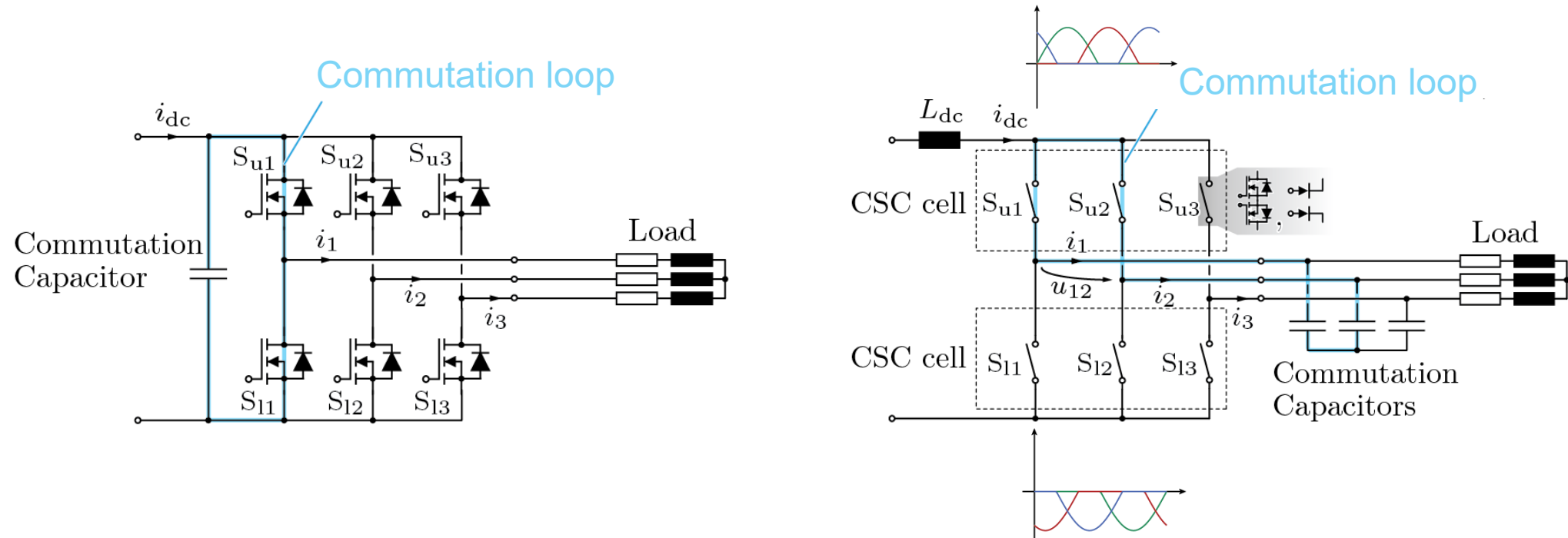
Ideal Pulsewise Currents

- Modern drive systems employ **WBG devices** (SiC/GaN) for higher control bandwidth
- However, **high dv/dt** causes insulation stress, EMI, and reliability concerns



Introduction: Voltage Source Inverter/Current Source Inverter

- CSI provides a **smooth line voltage** over motor windings → mitigates high dv/dt issues
- Output capacitors naturally filter → reduces EMI, insulation stress, bearing currents

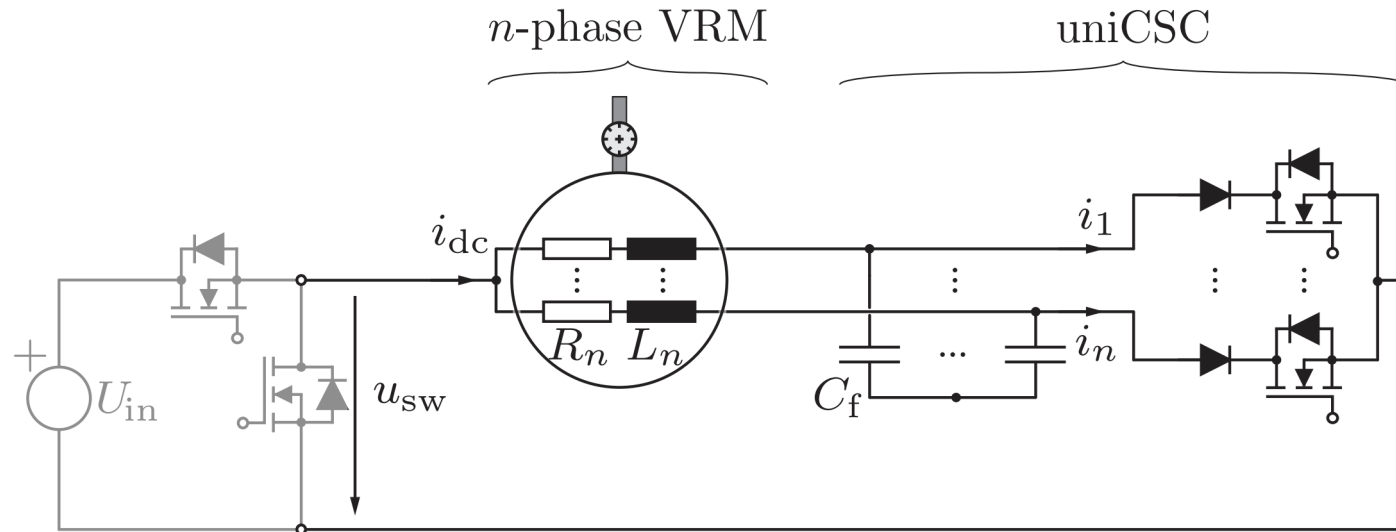


- Operation unit is not a leg but arm-cell → each arm-cell inherently processes **unipolar phase currents**



Introduction: Proposed Converter – *uniCSI*

- Simple, Scalable, and Low-cost structure



- 1 switching device + 1 diode per phase
- No bulky input inductor
- All switches at the same potential → low-cost gate driver circuit design
- Compatible with carrier-based PWM → simple drive implementation



Content

- ▶ Topology Derivation
- ▶ Modulation Method
- ▶ Simulation Results
- ▶ Conclusions



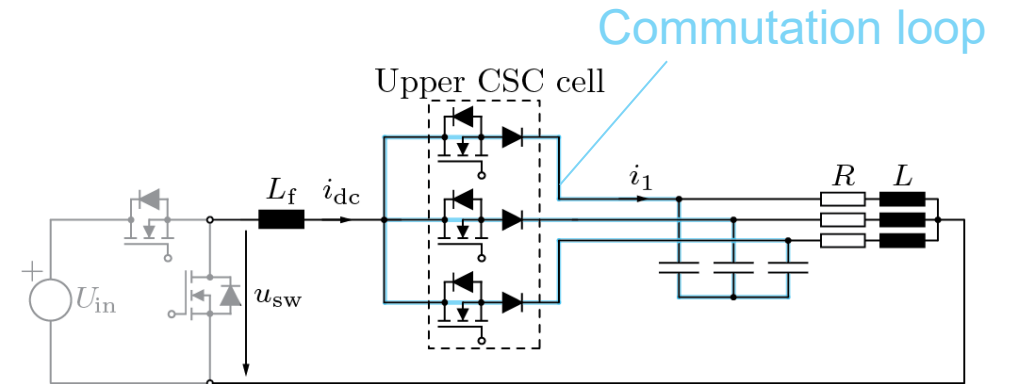
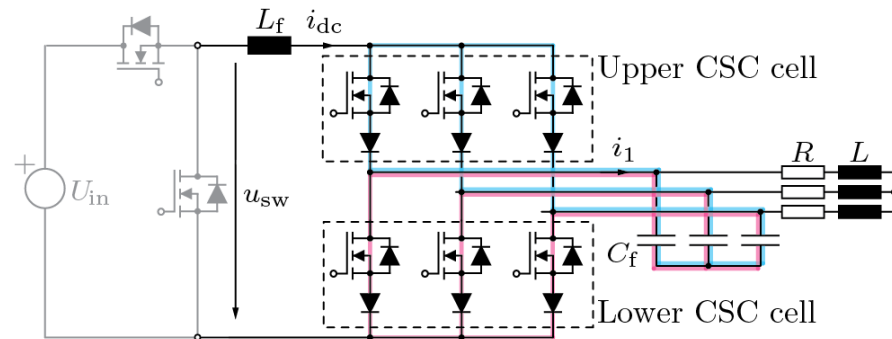
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Topology Derivation

- Conventional CSI: both upper and lower devices in each CSC cell process AC-current

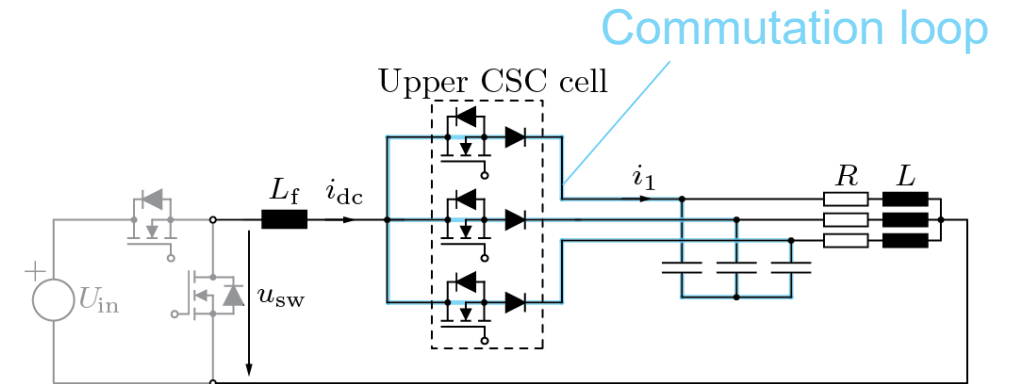
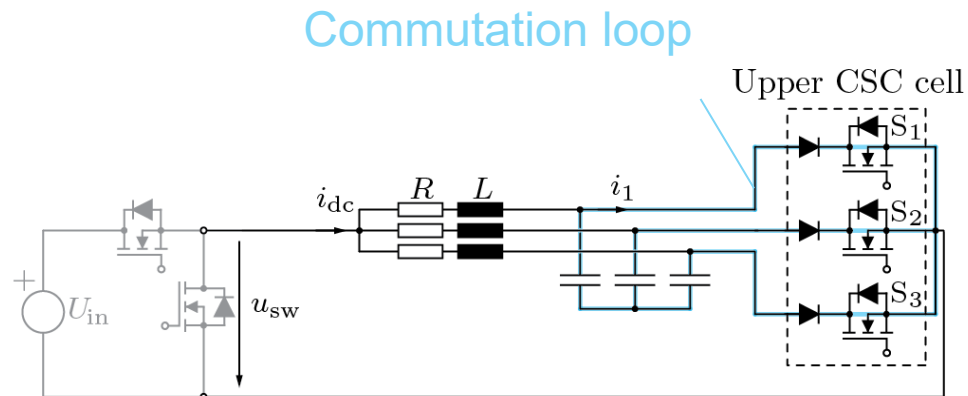


- Proposed simplification: remove lower devices
- Only high-side arm devices process positive phase currents
- Current returns through star-point → DC-bus



Topology Derivation

- Exchange order of CSC cell and load connection



- DC-link inductor replaced by **motor phase inductance**
- All switching devices share the **same source potential**
- Completed proposed topology – simple, scalable, and low-cost



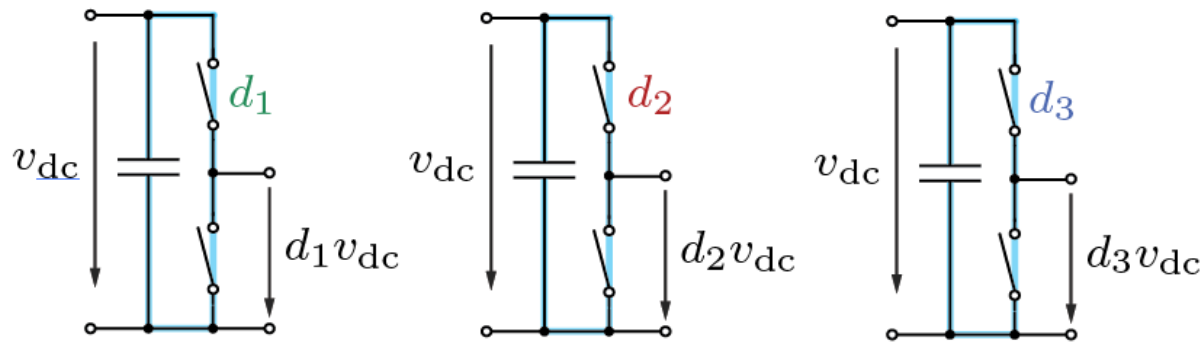
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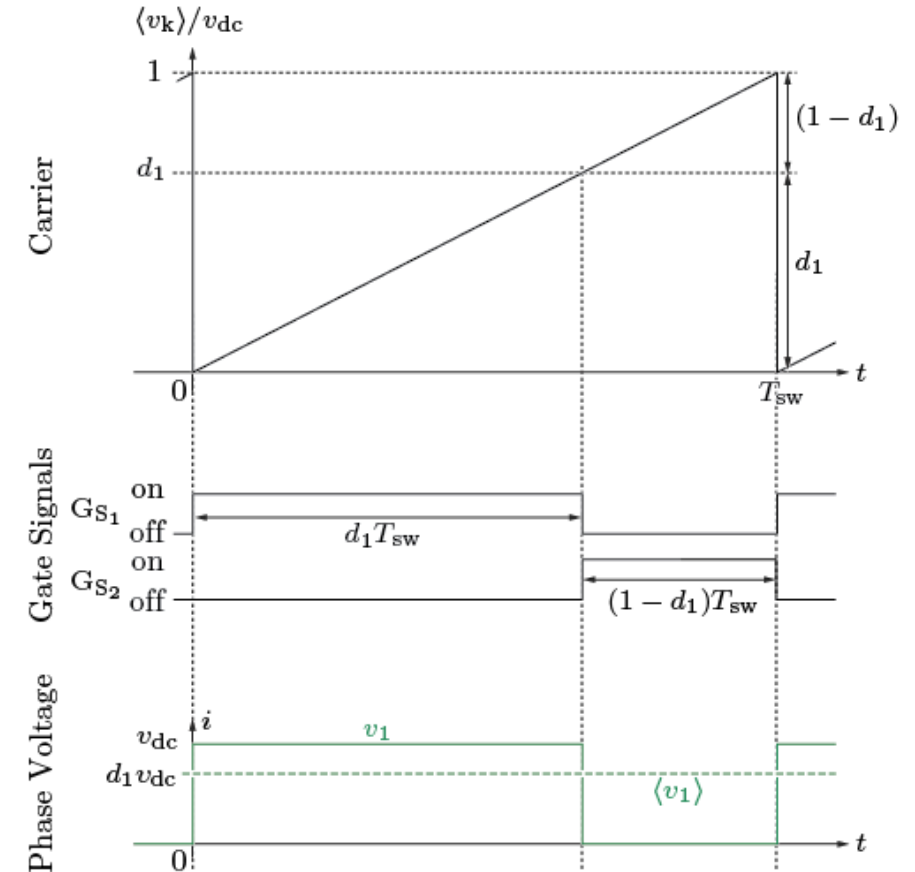


Carrier-Based Modulator for VSI

- Commutation occurs between **DC-link capacitor** and **switching leg**



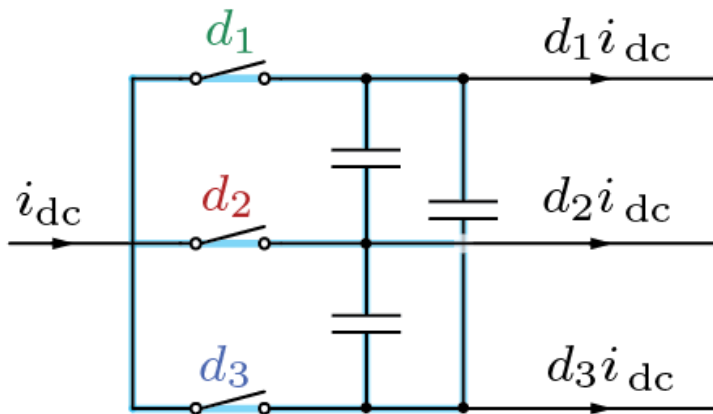
- Each phase is **independent** from the others in terms of commutation
- Output average voltage is controlled by duty ratio relative to the carrier
- Enables simple carrier-based PWM for sinusoidal voltage synthesis



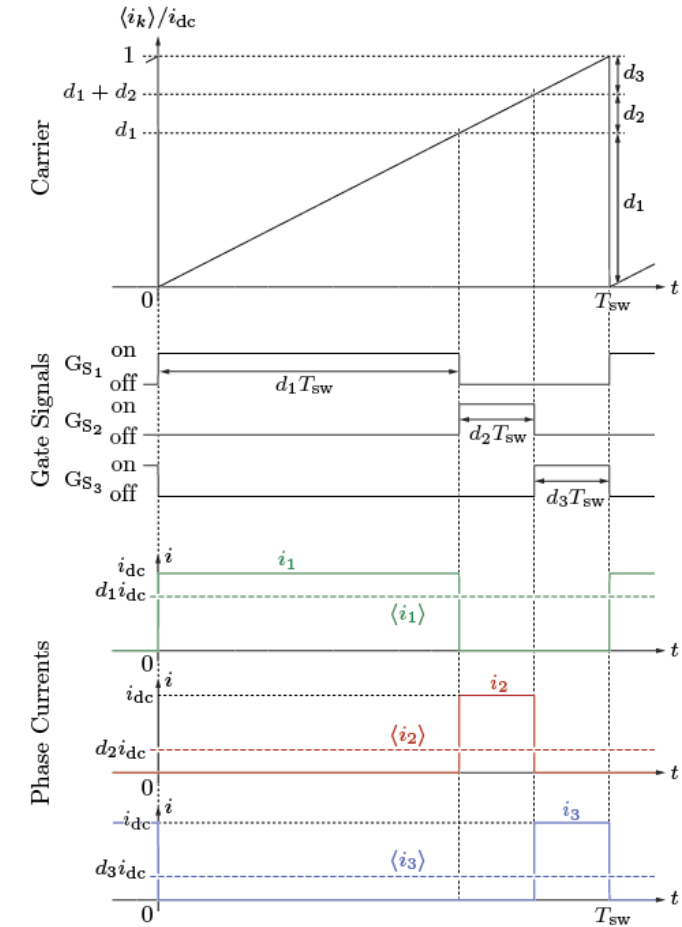


Carrier-Based Modulator for CSC

- Commutation occurs through output capacitors → phases are **coupled**
- Duty cycle must satisfy $\Sigma d = 1$ → **phase current cannot be controlled independently**



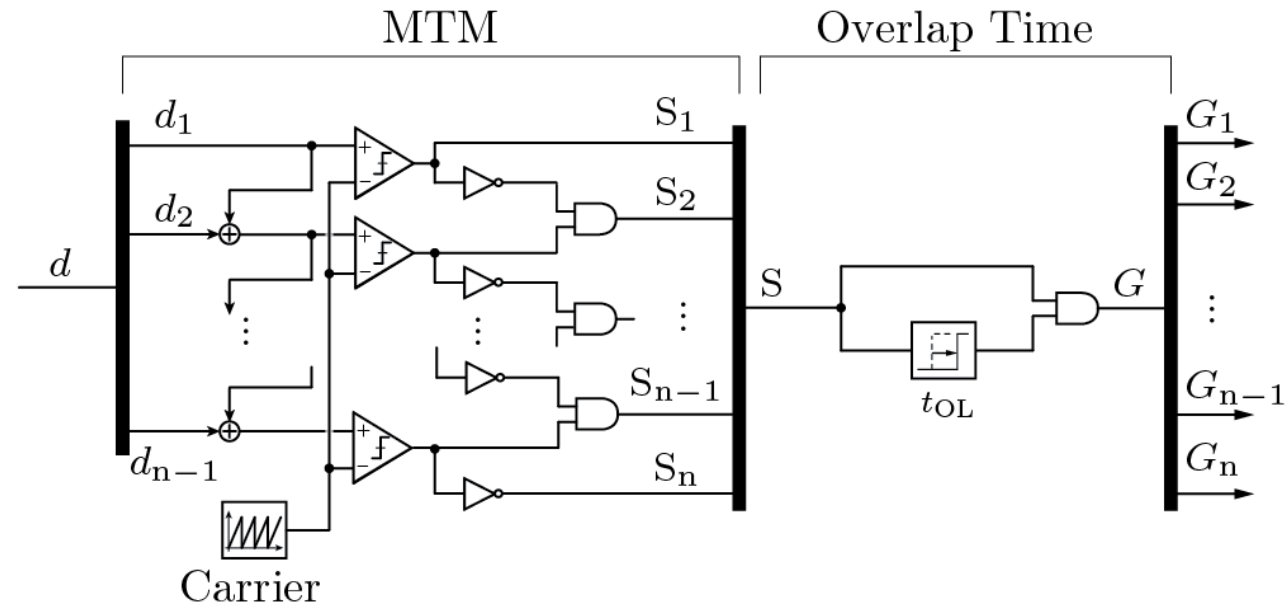
- Developed Multi-threshold Carrier-based Modulator (MTM)
 - Splits carrier into thresholds to allocate duty among phases
 - Achieves simple **carrier-based PWM** for CSC





Carrier-Based Modulator for CSC: Multi-Threshold-Modulator (MTM)

- Modular structure – identical cell repeated for each cell
- Duty allocation achieved by **multi-threshold comparison** with a single carrier



- Naturally **scalable** to arbitrary number of phases
- Enables carrier-based PWM for CSC with simple digital implementation



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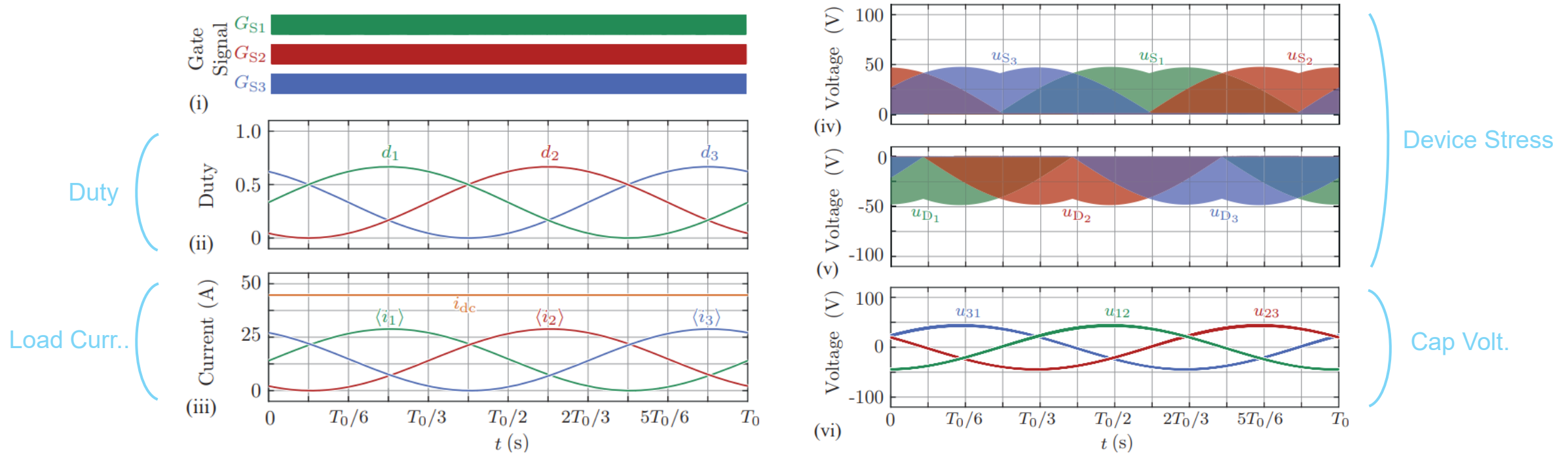
Parameter	Symbol	Value
Input current	i_{dc}	40 A
Output capacitance	C_f	4.7 μ F
Load resistance	R	1 Ω
Load inductance	L	3.5 mH
Switching frequency	f_{sw}	200 kHz
Fundamental frequency	$f_0 = 1/T_0$	50 Hz

TABLE I: Simulation Parameters.



Simulation Result: Sinusoidal Operation

- Phase current amplitude proportional to duty cycle → confirms CS operation
- Device voltage stress appears as line-to-line voltage across output capacitors

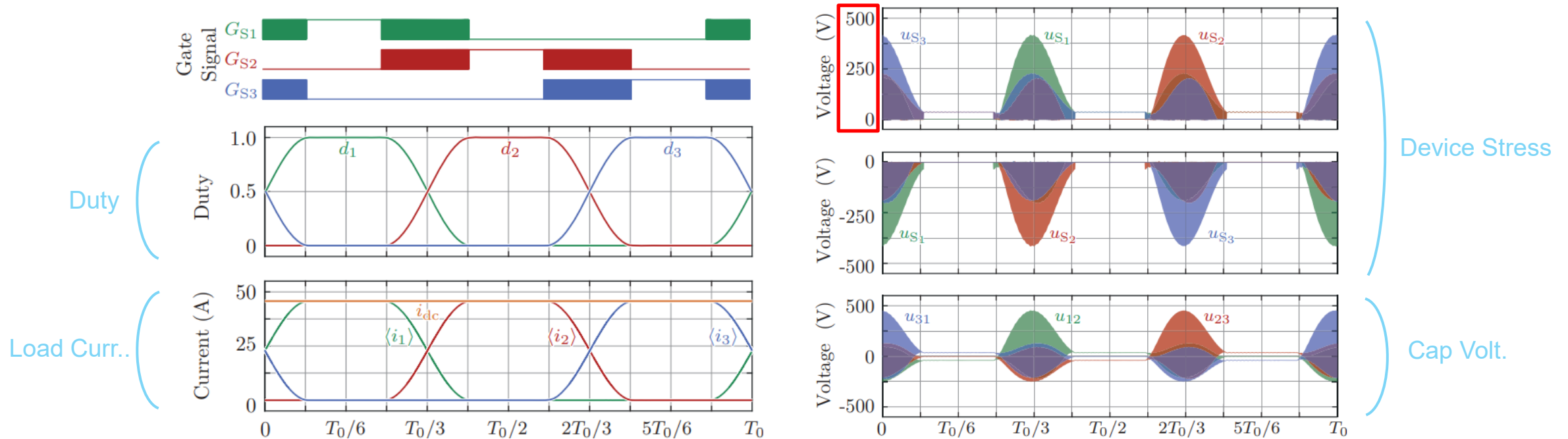


- Stress level depends on **load conditions** inherited CSI characteristic
- Simulation validates feasibility of the proposed MTM-based CSC modulation



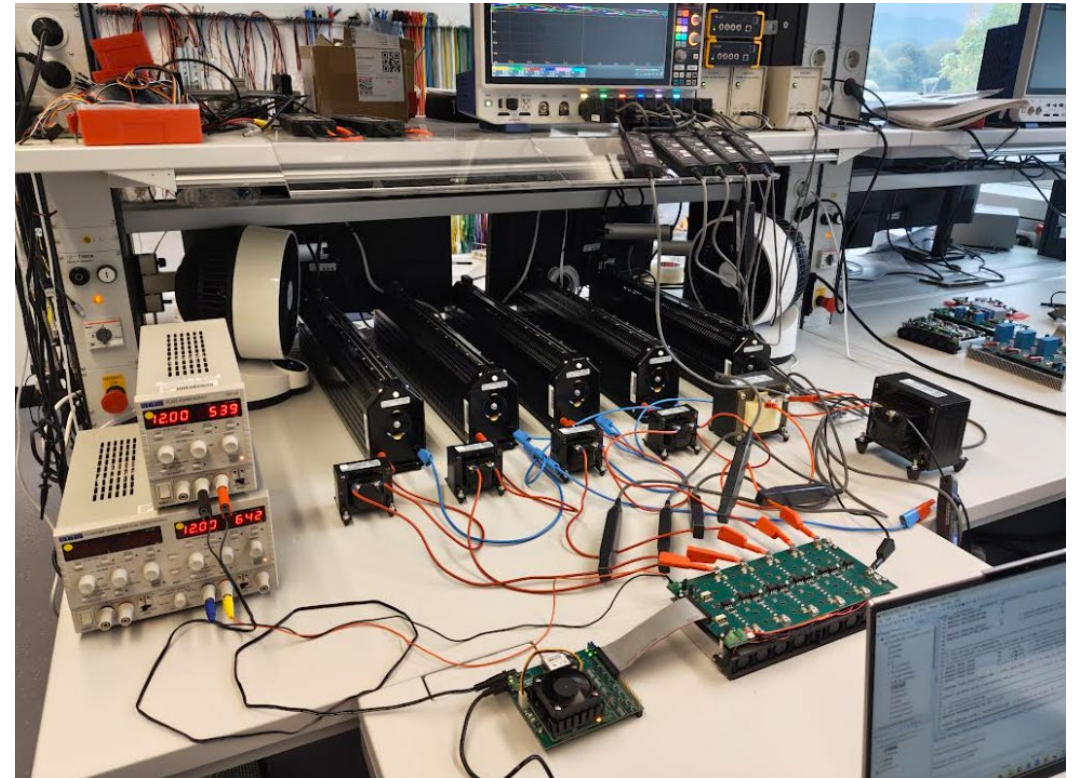
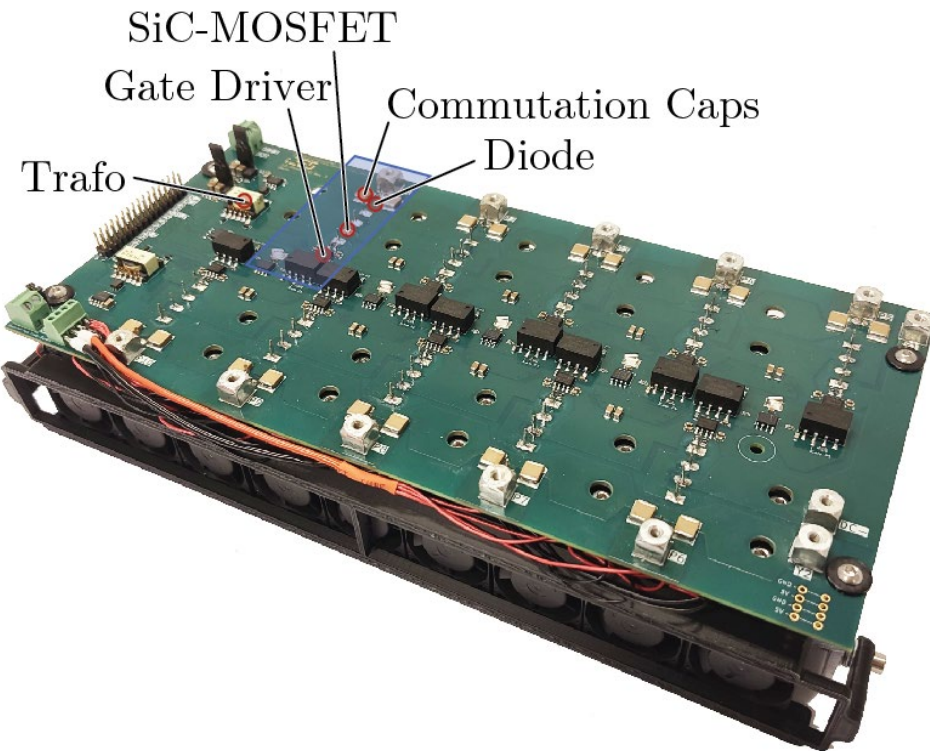
Simulation Result: Trapezoidal Operation

- Carrier-based method allows arbitrary current waveforms (e.g. trapezoidal)



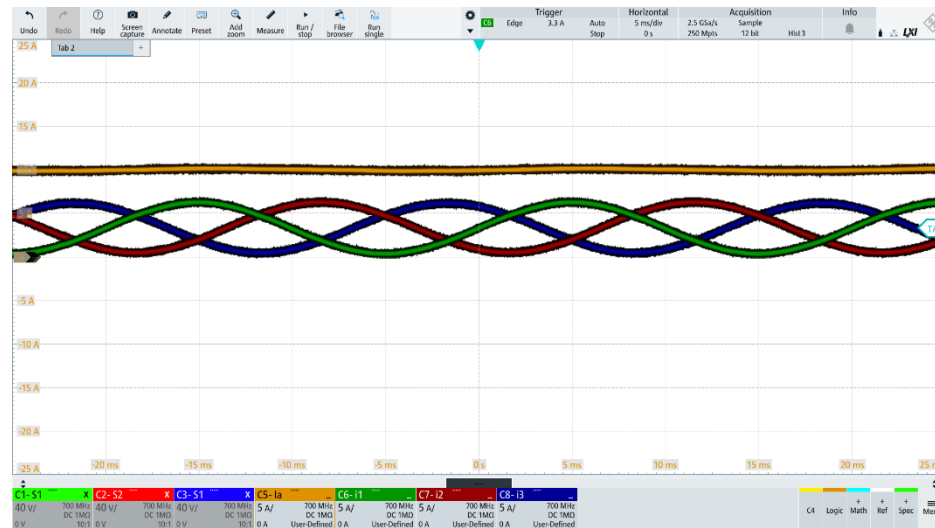
- Inductor energy is exchanged via capacitors \rightarrow **large voltage overshoot** observed
- Overshoot magnitude depends on **passive component** and **di/dt**
- Further investigation required for reliable design and operation

Hardware Implementation: 10-phase uniCSI

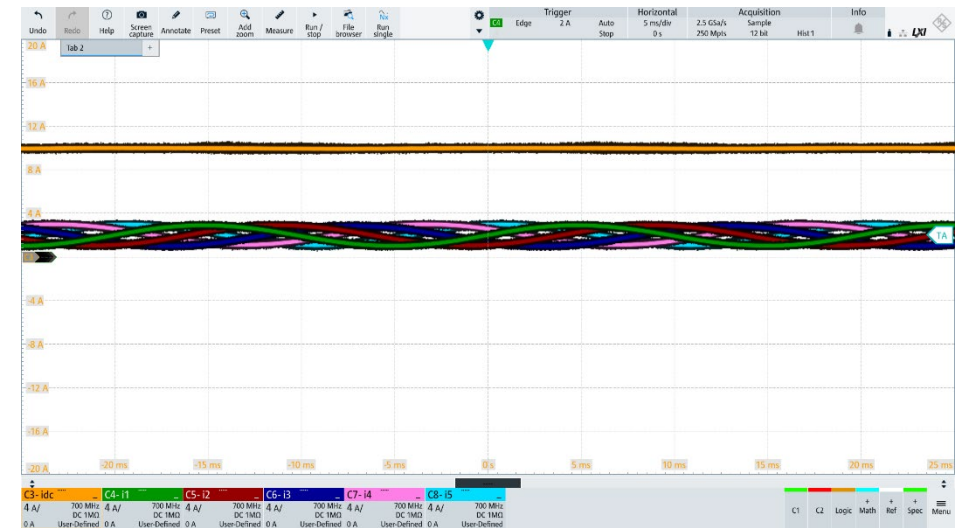




Hardware Implementation: 10-phase uniCSI



3-phase @ 10 A



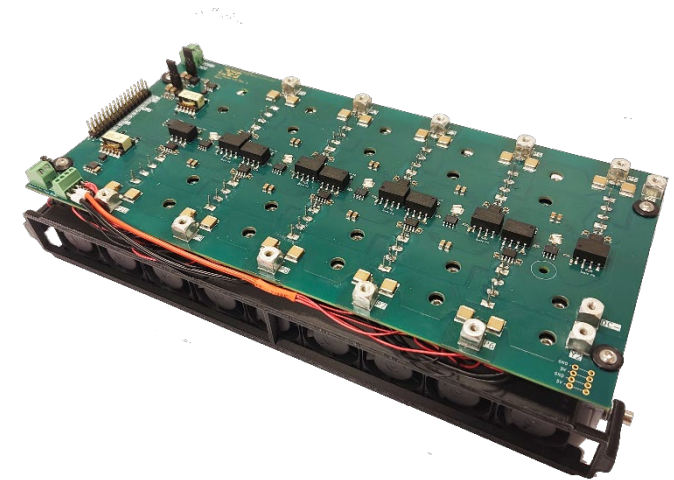
5-phase @ 10 A

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Conclusions

- Introduced a new **CSI-based converter topology** for VRM drives
- Achieves simple, scalable, and low-cost structure
 - Only one switch + one diode per phase
 - All switches share the same potential → reduced gate driver cost
- Developed modulation method using **Multi-Threshold Moduator (MTM)** → enables carrier-based PWM for CSC
- Simulation confirmed:
 - Phase current proportional to duty cycle (CSI operation)
 - Arbitrary waveforms drive (e.g. trapezoidal) feasible
- Observed capacitor voltage overshoot depends on passive components & di/dt
- Future work: **voltage stress management**, **integrating the whole system**



Thank you!

